

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of :
Kazuya Hizawa : Attn: Applications Branch
Continuation of Serial No.: 10/283,189 : Attorney Docket No. OKI.390D
Filed: February 19, 2004 :
For: A METHOD FOR FABRICATING A SEMICONDUCTOR DEVICE HAVING A
METALLIC SILICIDE LAYER

PRELIMINARY AMENDMENT

U.S. Patents and Trademark Office
2011 South Clark Place
Customer Window, **Mail Stop Patent Application**
Crystal Plaza Two, Lobby, Room 1B03
Arlington, VA 22202

Date: February 19, 2004

Sir:

Preliminary to the examination of the above-identified application, please enter the following amendments and remarks.

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 5 of this paper.

Remarks/Arguments begin on page 8 of this paper.